

**Vishay Semiconductors** 

### Hyperfast Rectifier, 8 A FRED Pt<sup>®</sup>





2L TO-220AC Base cathode 2 Q 30 Cathode Anode



**VS-8E2TH06** 

Cathode Anode VS-8E2TH06FP

**01** 

20

PRODUCT SUMMARY						
Package	2L TO-220AC, 2L TO-220 FP					
I <sub>F(AV)</sub>	8 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	2.5 V					
t <sub>rr</sub> (typ.)	17 ns					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					

#### **FEATURES**

- Hyperfast recovery time, reduced Qrr and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- True 2 pin package
- · Low forward voltage drop
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- · Designed and gualified for industrial level

#### **DESCRIPTION/APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the ac-to-dc section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	1	T <sub>C</sub> = 133 °C	8	•			
FULL-PAK	IF(AV)	T <sub>C</sub> = 78 °C	0				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	70	A			
Peak repetitive forward current	I <sub>FM</sub>		16				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	VF	I <sub>F</sub> = 8 A	-	2.1	2.5	V		
	۷F	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.6	1.9			
Deverse leekees eurrent	1	$V_{R} = V_{R}$ rated	-	0.2	35			
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	50	350	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	6	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		



HALOGEN FREE



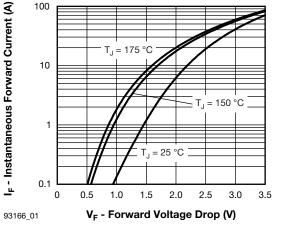
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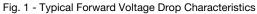
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt	= 100 A/µs, V <sub>R</sub> = 30 V	-	17	23		
		I <sub>F</sub> = 8.0 A, dI <sub>F</sub> /dt	= 100 A/µs, V <sub>R</sub> = 30 V	-	22	25		
		T <sub>J</sub> = 25 °C	$I_F = 8 A$	-	22	-		
Reverse recovery time	t <sub>rr</sub>		dl <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	43	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 600 A/μs V <sub>R</sub> = 390 V	-	33	-		
		T <sub>J</sub> = 25 °C	$I_F = 8 A$	-	3.1	-		
Peak recovery current	I <sub>BBM</sub>		— dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	5.2	-	А	
Peak recovery current	KKM	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 600 A/µs V <sub>R</sub> = 390 V	-	13	-	~	
Reverse recovery charge		T <sub>J</sub> = 25 °C	$I_F = 8 A$	-	32	-		
	rse recovery charge Q <sub>rr</sub>		dl <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	120	-	nC	
	Qrr	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 600 A/μs V <sub>R</sub> = 390 V	-	230	-		

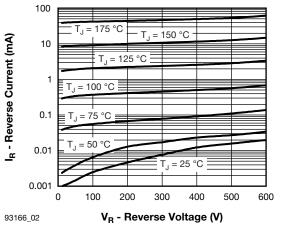
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C		
Thermal resistance,	Р		-	2	2.4			
junction to case FULL-PAK	R <sub>thJC</sub>		-	5	5.5			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-			
Walaht			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
		Case style TO-220		8E2TH06 8E2TH06FP				
Marking device		Case style TO-220 FULL-PAK						



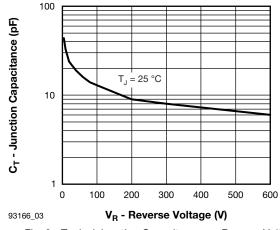
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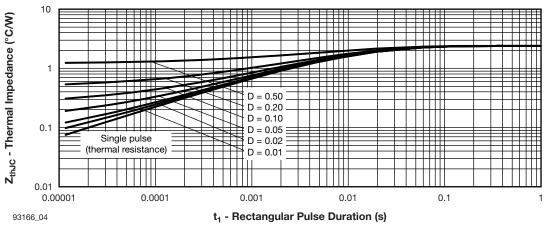
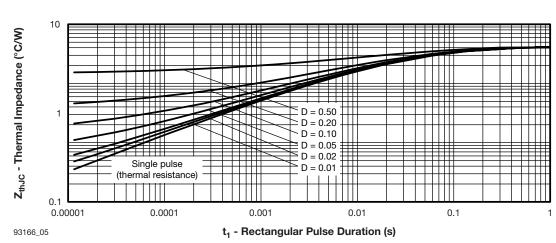


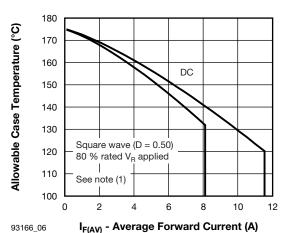
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (TO-220)



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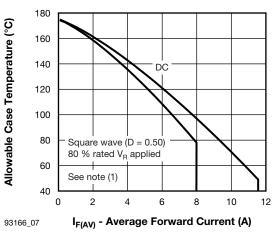


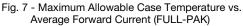


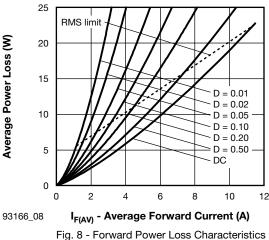




Average Forward Current (TO-220)







# Fig. 8 - Forward Power Loss Characteristics

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = Rated  $V_R$ 



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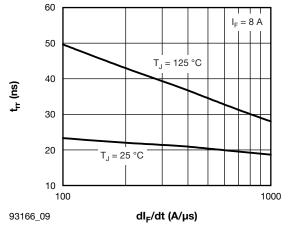


Fig. 9 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

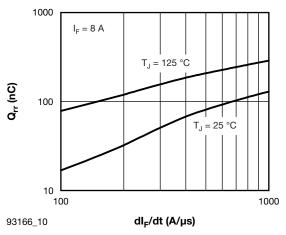


Fig. 10 - Typical Stored Charge vs.  $dI_F/dt$ 

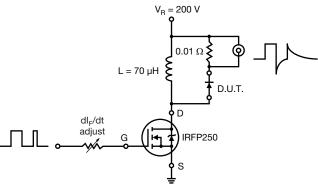
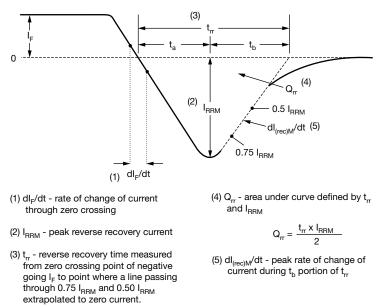
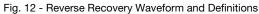


Fig. 11 - Reverse Recovery Parameter Test Circuit





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#### ORDERING INFORMATION TABLE

Device code	vs-	8	Е	2	т	Н	06	FP	-E
		2	3	4	5	6	7	8	9
	<ol> <li>Vishay Semiconductors product suffix</li> <li>Current rating (8 = 8 A)</li> </ol>								
	3 - Circuit configuration: E = Single diode								
	4 -		•	pin pack	age				
	5 -	T =	TO-220	)					
	6 -	H =	Hyperfa	ast recov	very tim	е			
	7 -	Volt	age coo	de (06 =	600 V)				
	8 - • None = TO-220								
		• F	P = FUI	_L-PAK					
	9 -	Env	rironmer	ntal digit	:				
		• -	E = Ro⊦	IS comp	liant an	d termir	nations I	ead (Pb	)-free

• -M = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCR							
VS-8E2TH06-E	50	1000	Antistatic plastic tubes				
VS-8E2TH06-M	50	1000	Antistatic plastic tubes				
VS-8E2TH06FP-E	50	1000	Antistatic plastic tubes				

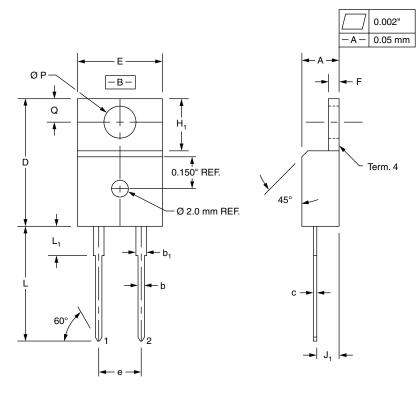
LINKS TO RELATED DOCUMENTS						
Dimensions	TO-220AC	www.vishay.com/doc?95259				
Dimensions	TO-220 FULL-PAK	www.vishay.com/doc?95260				
Part marking information	TO-220AC	www.vishay.com/doc?95391				
Fait marking mornation	TO-220 FULL-PAK	www.vishay.com/doc?95392				
Packaging information		www.vishay.com/doc?95388				

Vishay High Power Products

### True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches

VISHAY



SYMBOL	MILLIN	IETERS	INCH	ES	
STMDUL	MIN.	MAX.	MIN.	MAX.	
A	4.32	4.57	0.170	0.180	
b	0.71	0.91	0.028	0.036	
b <sub>1</sub>	1.15	1.39	0.045	0.055	
С	0.36	0.53	0.014	0.021	
D	14.99	15.49	0.590	0.610	
E	10.04	10.41	0.395	0.410	
e	5.08	BSC	0.200 BSC		
F	1.22	1.37	0.048	0.054	
H <sub>1</sub>	5.97	6.47	0.235	0.255	
J <sub>1</sub>	2.54	2.79	0.100	0.110	
L	13.47	13.97	0.530	0.550	
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150	
ØP	3.79	3.88	0.149	0.153	
Q	2.60	2.84	0.102	0.112	

#### Notes

 $^{\left(1\right)}$  Lead dimension and finish uncontrolled in  $L_{1}$ 

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

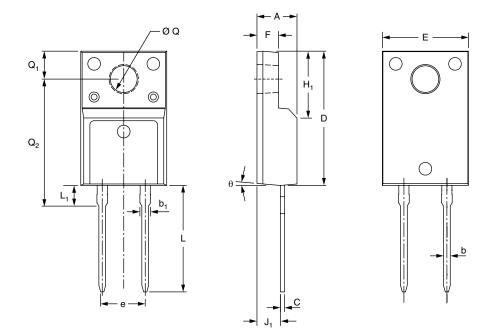
Controling dimension: Inch

Vishay High Power Products

# True 2 Pin TO-220 FULL-PAK

#### **DIMENSIONS** in millimeters and inches

**VISHAY** 



SYMPOL	MILLIN	METERS	INCH	IES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
e	5.08	typical	0.200 ty	ypical
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
Q2	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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